

<b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b>	<b>Application Number</b>	
	<b>Filing Date</b>	09/28/2004
	<b>First Named Inventor</b>	BAKKERS, Erik P. A. M.
	<b>Art Unit</b>	
	<b>Examiner Name</b>	
	<b>Attorney Docket Number</b>	NL02 0287 US

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. <sup>1</sup>	Document Number No.-Kind Code <sup>2</sup> (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns Lines, Where Relevant Passages or Relevant Figures Appear
		US-			
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FOREIGN PATENT DOCUMENTS						
Examiner Initials*	Cite No. <sup>1</sup>	Document Number (ctry <sup>3</sup> -no. <sup>4</sup> -kind <sup>5</sup> , if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of cited document	Pages, Columns Lines, Where Relevant Passages or Relevant Figures Appear	T <sup>6</sup>
MA		EP 0 544 408	06-02-1993	SHERIDON, NICHOLAS, ET AL.		

NON-PATENT LITERATURE DOCUMENTS						
Examiner Initials*	Cite No. <sup>1</sup>	Include name of the author (in capital letters), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.				T <sup>6</sup>
MA		NASSIOPOULOS, A G ET AL: "ELECTROLUMINESCENT SOLID STATE DEVICES BASED ON SILICON NANOWIRES, FABRICATED BY USING LITHOGRAPHY AND ETCHING TECHNIQUES" THIN SOLID FILS, ELSEVIER-SEQUOIS S.A. LAUSANNE, CH., VOL. 297, NO. 1-2, 1 APRIL 1997				
MA		HE ET AL: "DISPERSION, REFINEMENT, AND MANUPULATION OF SINGLE SILICON NANOWIRES" APPLIED PHYSICS LETTERS, VOL. 80, NO. 10, 11 MARCH 2002				

<b>Examiner Signature</b>	/Maki Angadi/	<b>Date Considered</b>	06/19/2006
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<sup>1</sup> Unique citation designation number. <sup>2</sup> See attached Kinds of U.S. Patent Documents. <sup>3</sup> Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). <sup>4</sup> For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number